

Feature

- Chips are electrically insulated from plate
- Package in compliance with international standard. Pressure type, excellent temperature characteristics and power cycling capability
- 350A below modules are forced air cooling, 400A above modules
Can be selected by air cooling or water cooling

Typical application

- AC/DC motor control, Different kind of rectifying power supply
- Industrial heating and control, Light adjustment, Non-contact switch
- Motor softstarter, Static reactive power compensation
- Welding equipment, Frequency transformation, UPS, Battery charging and discharging

I _{T(AV)}	55A
V _{DRM/V_{RRM}}	500-2500V
I _{TSM}	1.25 KA
I ² t	7.8 10 ³ a ² s

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _J (°C)	VALUE		UNIT
				Min	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave, 50HZ Double side cooled, T _C =98°C	125		55	A
I _{T(RMS)}	RMS current		125		86	A
V _{DRM} V _{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V _{DRM} &V _{RRM} tp=10ms V _{DSM} &V _{RSM} =V _{DRM} &V _{RRM} +200V	125	500	2500	V
I _{DRM} I _{RRM}	Repetitive peak current	V _{DM} =V _{DRM} V _{RM} =V _{RRM}	125		8	mA
I _{TSM}	Surge on-state current	10ms half sine wave V _R =0.6V _{RRM}	125		1.25	KA
I ² t	I ² t for fusing coordination				7.80	A ^{2S*10}
V _{TO}	Threshold voltage				0.85	V
r _T	On-state slope resistance		125		3.47	mΩ
V _{TM}	Peak on-state voltage	I _{TM} =170A	25		1.10	V
dv/dt	Critical rate of rise of on-state voltage	V _{DM} =0.67V _{DRM}	125		800	V/us
di/dt	Critical rate of rise of on-state current	V _{DM} =67%V _{DRM} TO 1000A, Gate pulse tr≤0.5us I _{GM} =1.5A	125		50	A/us
I _{GT}	Gate trigger current	V _A =12V, I _A =1A	25	30	100	mA
V _{GT}	Gate trigger voltage			0.8	2.5	V
I _H	Holding current			20	150	mA
V _{GD}	Npn-trigger gate voltage	V _{DM} =0.67V _{DRM}	125	0.2		V
R _{th(j-c)}	Thermal impedance node to the shell	180 ° sine wave, single heat sink			0.530	°C/W
R _{th(c-h)}	Thermal impedance (shell to powder)	180 ° sine wave, single heat sink			0.2	°C/W
V _{iso}	Insulation voltage			2500		V
F _M	Mounting force (M5)				4	N-m
	Mounting force (M6)				6	N-m
T _{stq}	Stored temperature			-40	125	°C
W _t	Weight					g
Outline						

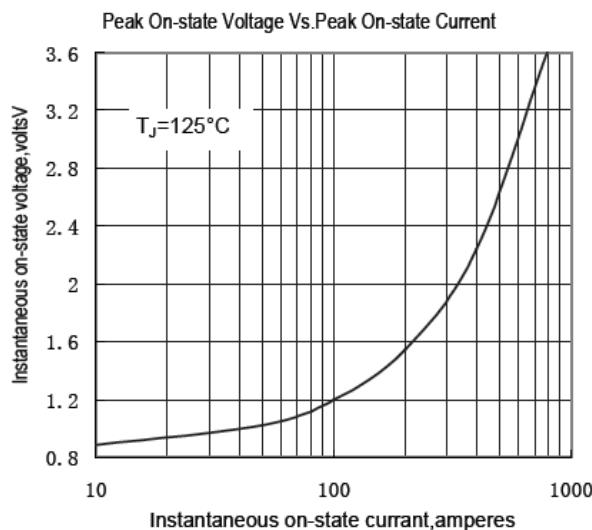


Fig.1

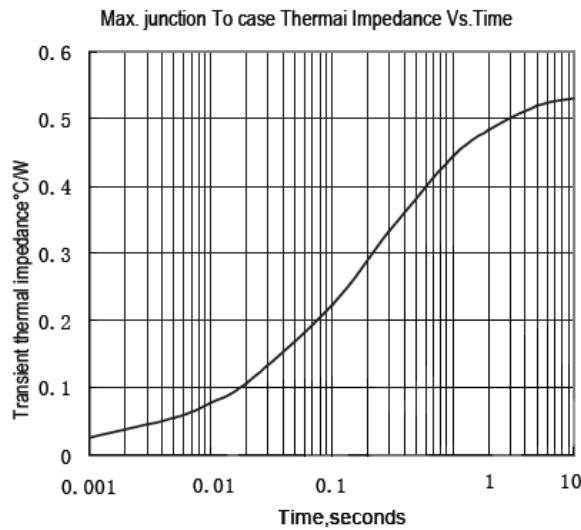


Fig.2

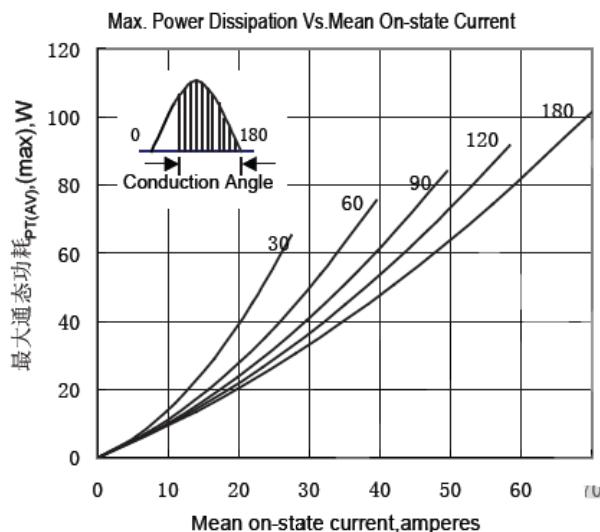


Fig.3

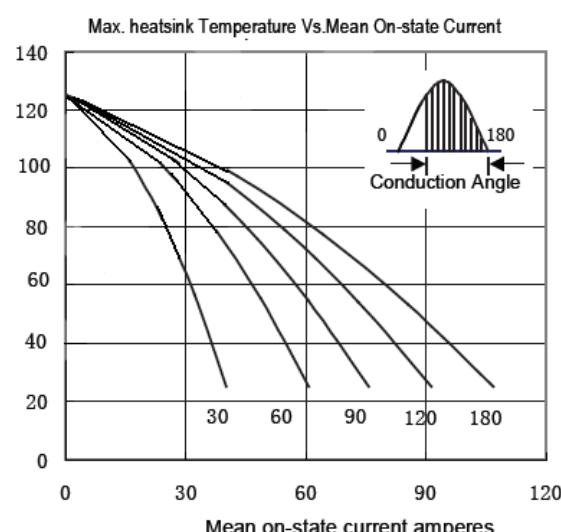


Fig.4

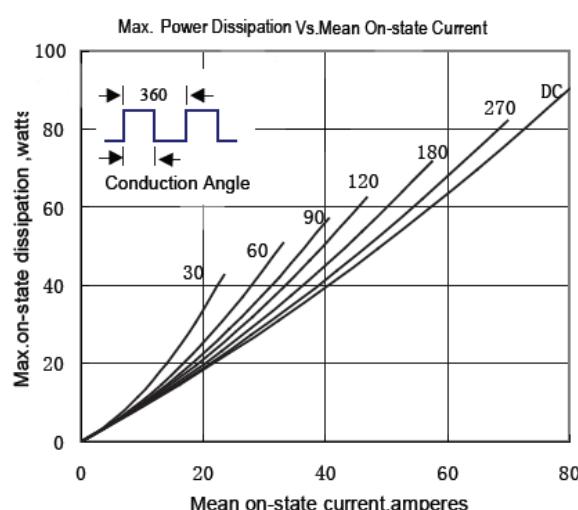


Fig.5

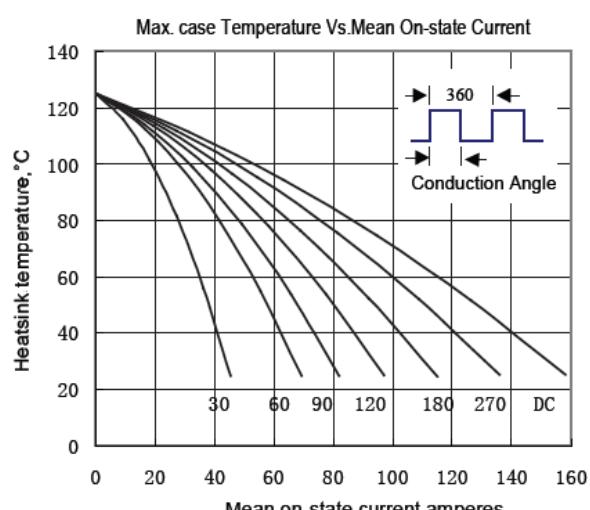


Fig.6

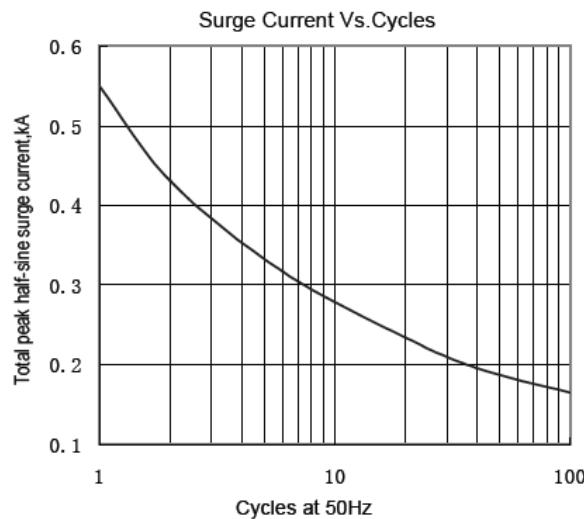


Fig.7

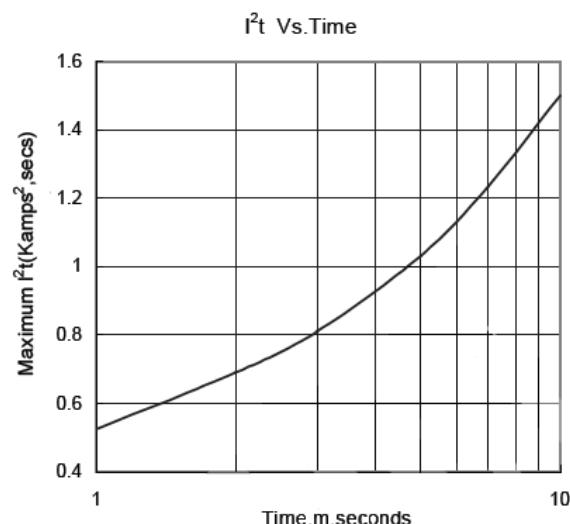


Fig.8

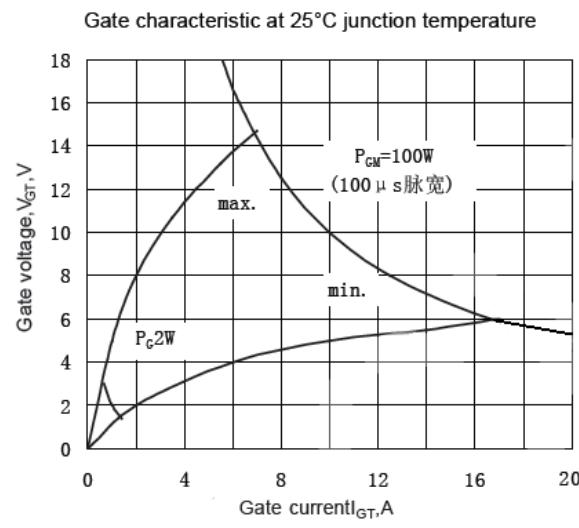


Fig.9

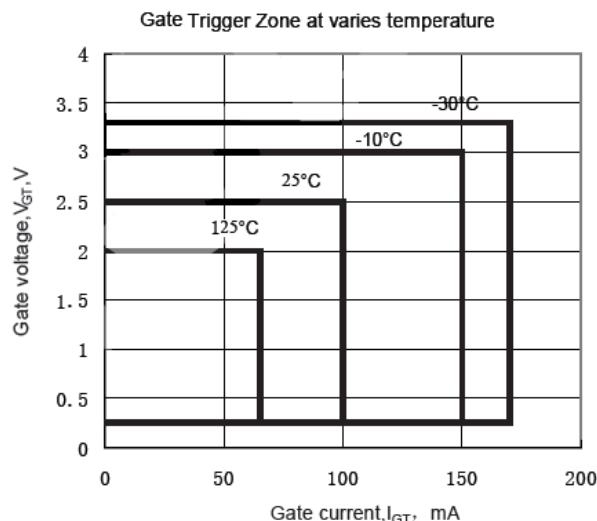
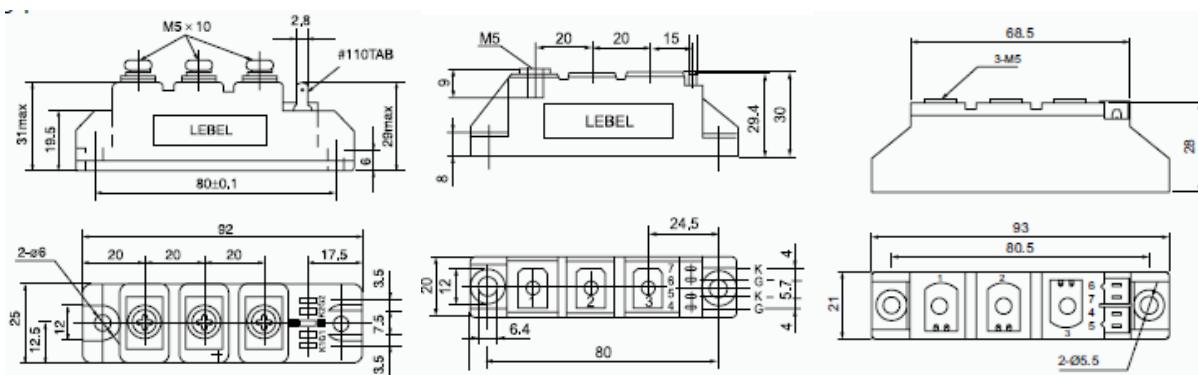


Fig.10

Outline:



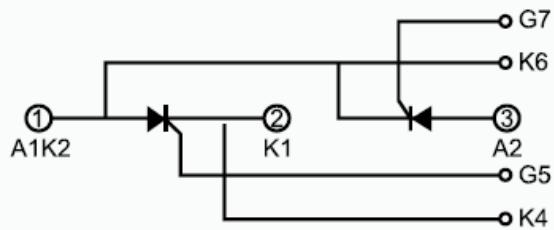
1

2

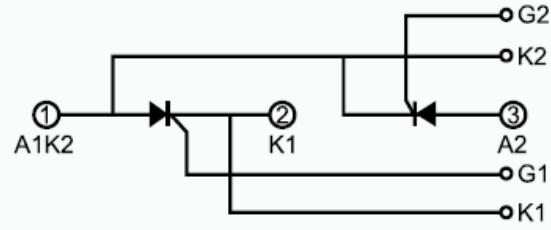
3

Circuit Drawing:

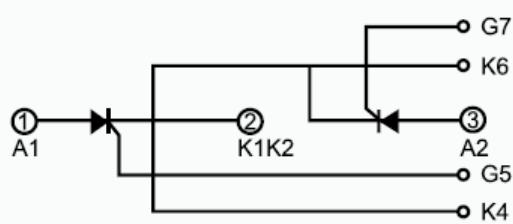
MTC 90A H20



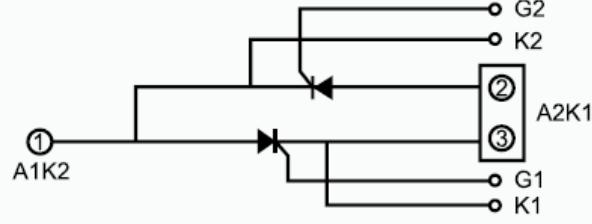
MTC 100A H25



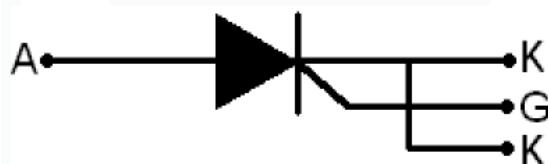
MTK



MTX



MT



MTA

